NSN 5962-01-530-9106

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в	ody Length:
	440 inches
	ody Width:
	285 inches
	ody Height:
	085 inches
М	aximum Power Dissipation Rating:
79	94.0 milliwatts
ο	perating Tempurature Range:
-5	5.0/+125.0 degrees celsius
S	torage Tempurature Range:
-6	5.0/+150.0 degrees celsius
E	nd Application:
F٠	15 aircraft avonics
F	eatures Provided:
Μ	onolithic and schottky and bipolar
In	closure Material:
С	eramic
In	closure Configuration:
FI	at pack
0	utput Logic Form:
Tı	ransistor-transistor logic
In	put Circuit Pattern:
10) input
С	ase Outline Source And Designator:
F٠	-5 mil-m-38510
Т	erminal Surface Treatment:
S	older
P	roduct Name:
Μ	icrocircuit, digital - 2048 bit bipolar prom
V	oltage Rating And Type Per Characteristic:
7.	0 volts power source
Ti	me Rating Per Chacteristic:
35	5.00 nanoseconds propagation delay time, low to high level output and 35.00 nanoseconds propagation delay time, high to low level
οι	utput
	emory Device Type:
E	prom
	emory Capacity:
	048 bit 512 word
	pecial Features:
	rogram using cage 82577 dwg pt5059100-03-03
Т	est Data Document:

81349-mil-m-38510 specification (includes engineering type bulletins, brochures, etc., that reflect specification type data in specification format; excludes commercial catalogs, industry directories, and similar trade publications, reflecting general type data on certain

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Terminal Type And Quantity:

16 flat leads

Specification Data:

81349-mil-m-38510/204 government specification

Shelf Life:

N/a

Unit Of Measure:

Demilitarization:

Yes - demil/mli

Fiig:

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